CY54/74FCT273T

8-Bit Register

SCCS020 - March 1995 - Revised February 2000

Features

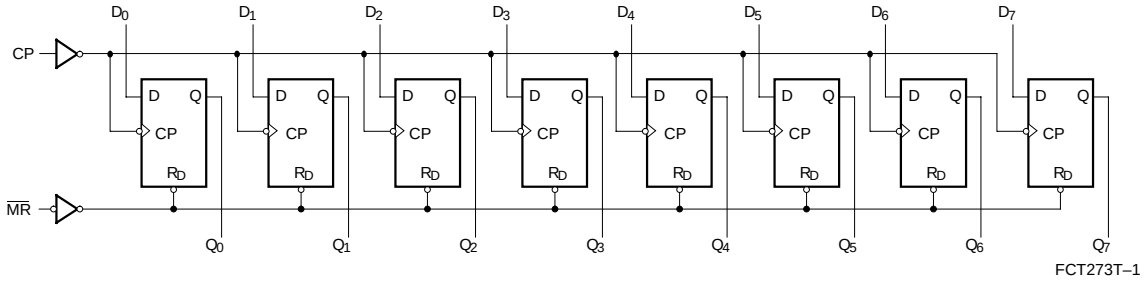
- **Function, pinout, and drive compatible with FCT and F logic**
- **FCT-C speed at 5.8 ns max. (Com'l)**
  FCT-A speed at 7.2 ns max. (Com'l)
- **Reduced V_{OH} (typically = 3.3V) versions of equivalent FCT functions**
- **Edge-rate control circuitry for significantly improved noise characteristics**
- **Power-off disable feature**
- **Matched rise and fall times**
- **ESD > 2000V**
- **Fully compatible with TTL input and output logic levels**
- **Extended commercial range of –40˚C to +85˚C**
- **Sink current 64 mA (Com'l), 32 mA (Mil)**
  Source current 32 mA (Com'l), 12 mA (Mil)

Functional Description

The FCT273T consists of eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered clock (CP) and master reset (MR) load and reset all flip-flops simultaneously. The FCT273T is an edge-triggered register. The state of each D input (one set-up time before the LOW-to-HIGH clock transition) is transferred to the corresponding flip-flop's Q output. All outputs will be forced LOW by a low voltage level on the $\overline{MR}$ input.

The outputs are designed with a power-off disable feature to allow for live insertion of boards.

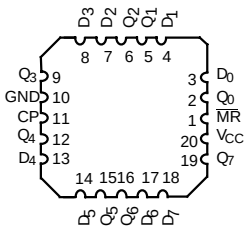
Logic Block Diagram



FCT273T–1

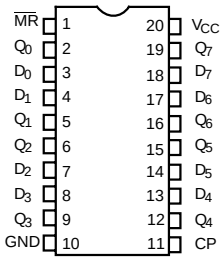
Pin Configurations

LCC
Top View



FCT273T–2

DIP/SOIC/QSOP
Top View



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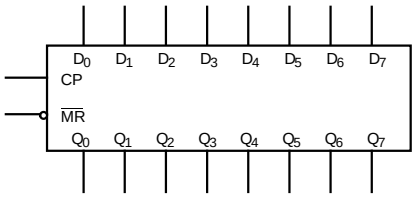
Logic Symbol



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Function Table[1]

Operating Mode	Inputs			Output
	$\overline{MR}$	CP	D	Q
Reset (clear)	L	X	X	L
Load '1'	H	⌐	h	H
Load '0'	H	⌐	l	L

Note:

1. H = HIGH Voltage Level steady state
   h = HIGH Voltage Level one set-up time prior to LOW-to-HIGH clock transition
   L = LOW Voltage Level steady state
   l = LOW Voltage Level one set-up time prior to the LOW-to-HIGH transition
   X = Don't Care
   ⌐ = LOW-to-HIGH clock transition

Maximum Ratings[2, 3]

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature .....–65°C to +150°C

Ambient Temperature with Power Applied.....–65°C to +135°C

Supply Voltage to Ground Potential.....–0.5V to +7.0V

DC Input Voltage .....–0.5V to +7.0V

DC Output Voltage .....–0.5V to +7.0V

DC Output Current (Maximum Sink Current/Pin).....120 mA

Power Dissipation 0.5W

Static Discharge Voltage.....>2001V (per MIL-STD-883, Method 3015)

Operating Range

Range	Range	Ambient Temperature	V_{CC}
Commercial	All	–40°C to +85°C	5V ± 5%
Military[4]	All	–55°C to +125°C	5V ± 10%

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions		Min.	Typ.[5]	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC}=Min., I_{OH}=–32 mA	Com'l	2.0			V
		V_{CC}=Min., I_{OH}=–15 mA	Com'l	2.4	3.3		V
		V_{CC}=Min., I_{OH}=–12 mA	Mil	2.4	3.3		V
V_{OL}	Output LOW Voltage	V_{CC}=Min., I_{OL}=64 mA	Com'l		0.3	0.55	V
		V_{CC}=Min., I_{OL}=32mA	Mil		0.3	0.55	V
V_{IH}	Input HIGH Voltage			2.0			V
V_{IL}	Input LOW Voltage					0.8	V
V_H	Hysteresis[6]	All inputs			0.2		V
V_{IK}	Input Clamp Diode Voltage	V_{CC}=Min., I_{IN}=–18 mA			–0.7	–1.2	V
I_I	Input HIGH Current	V_{CC}=Max., V_{IN}=V_{CC}				5	µA
I_{IH}	Input HIGH Current	V_{CC}=Max., V_{IN}=2.7V				±1	µA
I_{IL}	Input LOW Current	V_{CC}=Max., V_{IN}=0.5V				±1	µA
I_{OS}	Output Short Circuit Current[7]	V_{CC}=Max., V_{OUT}=0.0V		–60	–120	–225	mA
I_{OFF}	Power-Off Disable	V_{CC}=0V, V_{OUT}=4.5V				±1	µA

Capacitance[6]

Parameter	Description	Typ.[5]	Max.	Unit
C_{IN}	Input Capacitance	5	10	pF
C_{OUT}	Output Capacitance	9	12	pF

Notes:

2. Unless otherwise noted, these limits are over the operating free-air temperature range.
3. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V_{CC} or ground.
4. T_A is the "instant on" case temperature
5. Typical values are at V_{CC}=5.0V, T_A=+25°C ambient.
6. This parameter is specified but not tested.
7. Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parametric tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

Power Supply Characteristics

Parameter	Description	Test Conditions	Typ.[5]	Max.	Unit
I_{CC}	Quiescent Power Supply Current	V_{CC}=Max., $V_{IN} \le 0.2V$, $V_{IN} \ge V_{CC}$-0.2V	0.1	0.2	mA
ΔI_{CC}	Quiescent Power Supply Current (TTL inputs HIGH)	V_{CC}=Max., V_{IN}=3.4V, f_1=0, Outputs Open [8]	0.5	2.0	mA
I_{CCD}	Dynamic Power Supply Current[9]	V_{CC}=Max., One Bit Toggling, 50% Duty Cycle, Outputs Open, $\overline{MR}$=V_{CC}, $V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC}$-0.2V	0.06	0.12	mA/MHz
I_C	Total Power Supply Current[10]	V_{CC}=Max., f_0=10 MHz, 50% Duty Cycle, Outputs Open, One Bit Toggling at f_1=5 MHz, $\overline{MR}$=V_{CC}, $V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC}$-0.2V	0.7	1.4	mA
		V_{CC}=Max., f_0=10 MHz, 50% Duty Cycle, Outputs Open, One Bit Toggling at f_1=5 MHz, $\overline{MR}$=V_{CC}, V_{IN}=3.4V or V_{IN}=GND	1.2	3.4	mA
		V_{CC}=Max., f_0=10 MHz, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f_1=2.5MHz, $\overline{MR}$=V_{CC}, $V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC}$-0.2V	1.6	3.2[11]	mA
		V_{CC}=Max., f_0=10 MHz, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f_1=2.5 MHz, $\overline{MR}$=V_{CC}, V_{IN}=3.4V or V_{IN}=GND	3.9	12.2[11]	mA

Notes:

8. Per TTL driven input (V_{IN}=3.4V); all other inputs at V_{CC} or GND.
9. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
10. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
    $I_C = I_{CC}+\Delta I_{CC} D_H N_T + I_{CCD}(f_0/2 + f_1 N_1)$
    I_{CC} = Quiescent Current with CMOS input levels
    ΔI_{CC} = Power Supply Current for a TTL HIGH input (V_{IN}=3.4V)
    D_H = Duty Cycle for TTL inputs HIGH
    N_T = Number of TTL inputs at D_H
    I_{CCD} = Dynamic Current caused by an input transition pair (HLH or LHL)
    f_0 = Clock frequency for registered devices, otherwise zero
    f_1 = Input signal frequency
    N_1 = Number of inputs changing at f_1
    All currents are in milliamps and all frequencies are in megahertz.
11. Values for these conditions are examples of the I_{CC} formula. These limits are specified but not tested.

Switching Characteristics Over the Operating Range[12]

Parameter	Description	FCT273T		FCT273AT				Unit	Fig. No.[13]
		Commercial		Military		Commercial			
		Min.	Max.	Min.	Max.	Min.	Max.		
t_{PLH} t_{PHL}	Propagation Delay Clock to Output	2.0	13.0	2.0	8.3	2.0	7.2	ns	1, 5
t_{PLH} t_{PHL}	Propagation Delay $\overline{MR}$ to Output	2.0	13.0	2.0	8.3	2.0	7.2	ns	1, 6
t_S	Set-Up Time HIGH or LOW D to Clock	2.0		2.0		2.0		ns	4
t_H	Hold Time HIGH or LOW D to Clock	1.5		1.5		1.5		ns	4
t_W	Clock Pulse Width HIGH or LOW	6.0		6.0		6.0		ns	5
t_W	$\overline{MR}$ Pulse Width LOW	6.0		6.0		6.0		ns	6
t_{REC}	Recovery Time $\overline{MR}$ to Clock	2.0		2.5		2.0		ns	6

Parameter	Description	FCT273CT		Unit	Fig. No.[13]
		Commercial			
		Min.	Max.		
t_{PLH} t_{PHL}	Propagation Delay Clock to Output	2.0	5.8	ns	1, 5
t_{PLH} t_{PHL}	Propagation Delay $\overline{MR}$ to Output	2.0	6.1	ns	1, 6
t_S	Set-Up Time HIGH or LOW D to Clock	2.0		ns	4
t_H	Hold Time HIGH or LOW D to Clock	1.5		ns	4
t_W	Clock Pulse Width HIGH or LOW	6.0		ns	5
t_W	$\overline{MR}$ Pulse Width LOW	6.0		ns	6
t_{REC}	Recovery Time $\overline{MR}$ to Clock	2.0		ns	6

Ordering Information

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
5.8	CY74FCT273CTQCT	Q5	20-Lead (150-Mil) QSOP	Commercial
	CY74FCT273CTSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC	
7.2	CY74FCT273ATQCT	Q5	20-Lead (150-Mil) QSOP	Commercial
	CY74FCT273ATSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC	
8.3	CY54FCT273ATLMB	L61	20-Square Leadless Chip Carrier	Military
	CY54FCT273ATDMB	D6	20-Lead (300-Mil) CerDIP	
13.0	CY74FCT273TQCT	Q5	20-Lead (150-Mil) QSOP	Commercial
	CY74FCT273TSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC	

Notes:
12. Minimum limits are specified but not tested on Propagation Delays.
13. See “Parameter Measurement Information” in the General Information section.

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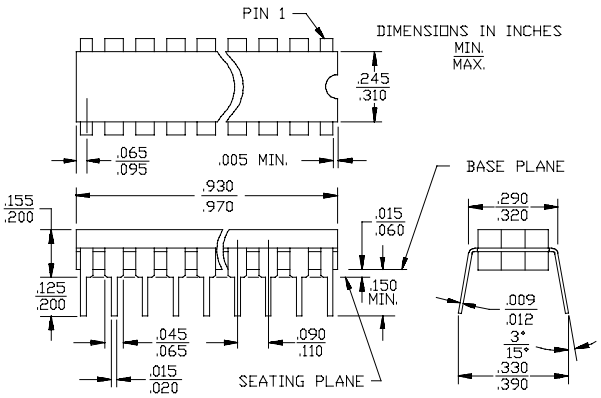
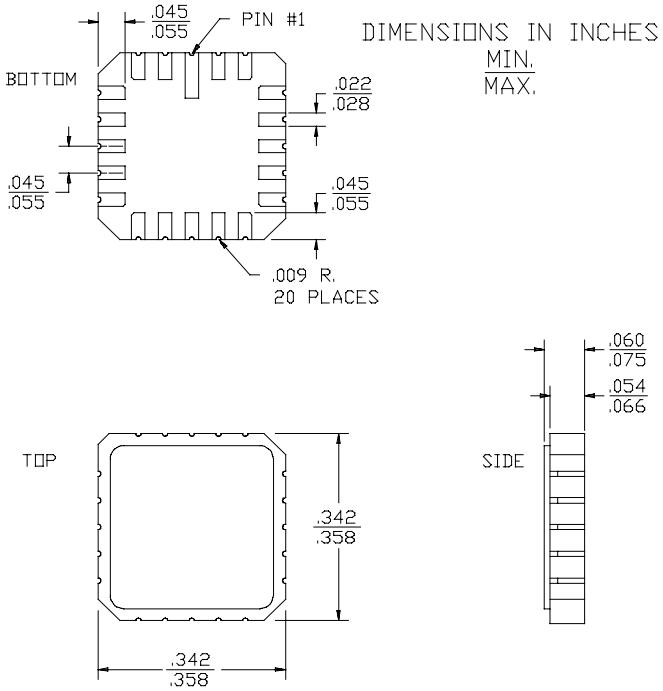
Package Diagrams

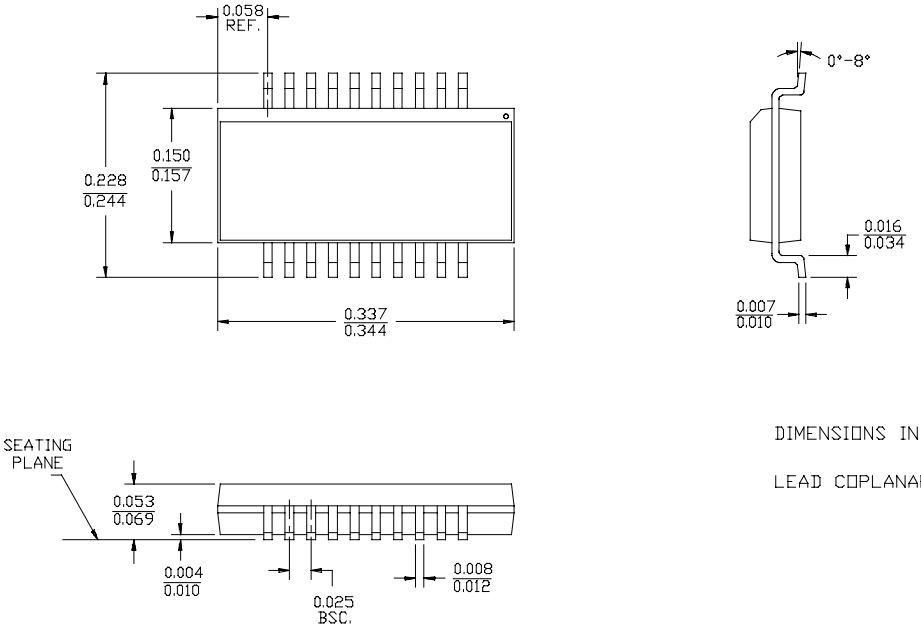
20-Lead (300-Mil) CerDIP D6
MIL-STD-1835 D- 8 Config.A



20-Pin Square Leadless Chip Carrier L61
MIL-STD-1835 C-2A

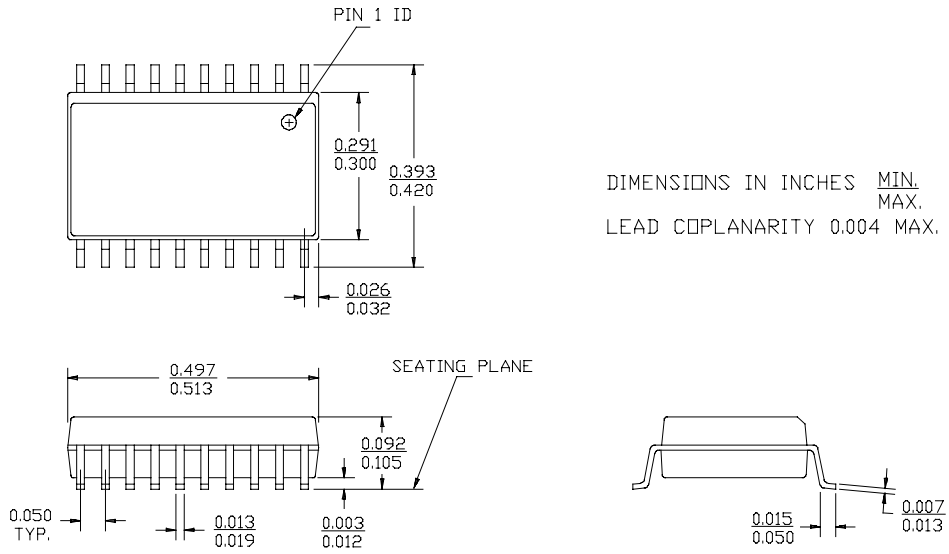


20-Lead Quarter Size Outline Q5



Package Diagrams (continued)

20-Lead (300-Mil) Molded SOIC S5



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